



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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CMOSH-4E

**ENHANCED SPECIFICATION
SURFACE MOUNT SILICON
SCHOTTKY DIODE**



www.centrasemi.com



SOD-523 CASE

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMOSH-4E is an enhanced version of the CMOSH-3 silicon Schottky diode in an SOD-523 surface mount package.

MARKING CODE: 4E

ENHANCED SPECIFICATIONS:

- ◆ I_F from 100mA MAX to 200mA MAX
- ◆ BV_R from 30V MIN to 40V MIN
- ◆ V_F from 1.0V MAX to 0.8V MAX

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

- ◆ **Peak Repetitive Reverse Voltage**
- ◆ **Continuous Forward Current**
Peak Repetitive Forward Current
Peak Forward Surge Current, $t_p=10\text{ms}$
Power Dissipation
Operating and Storage Junction Temperature
Thermal Resistance

SYMBOL

SYMBOL	UNITS
V_{RRM}	40 V
I_F	200 mA
I_{FRM}	350 mA
I_{FSM}	750 mA
P_D	250 mW
T_J, T_{stg}	-65 to +150 °C
Θ_{JA}	500 °C/W

ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I_R	$V_R=25\text{V}$		90	500	nA
I_R	$V_R=25\text{V}, T_A=100^\circ\text{C}$		25	100	μA
◆ BV_R	$I_R=100\mu\text{A}$	40	50		V
V_F	$I_F=2.0\text{mA}$		0.29	0.33	V
◆ V_F	$I_F=15\text{mA}$		0.37	0.42	V
◆ V_F	$I_F=100\text{mA}$		0.51	0.80	V
◆◆ V_F	$I_F=200\text{mA}$		0.65	1.0	V
C_J	$V_R=1.0\text{V}, f=1.0\text{MHz}$		7.0		pF
t_{rr}	$I_F=I_R=10\text{mA}, I_{rr}=1.0\text{mA}, R_L=100\Omega$			5.0	ns

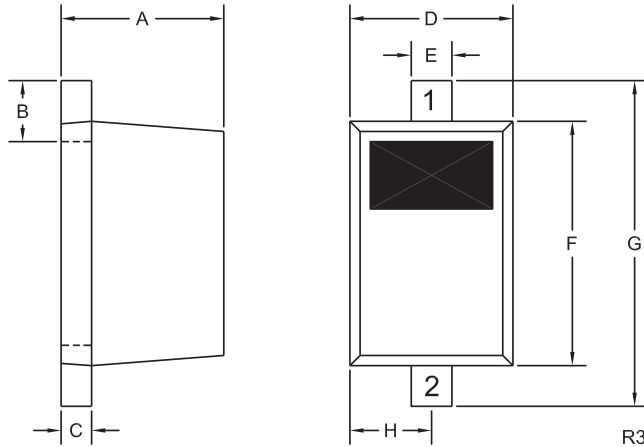
- ◆ Enhanced specification.
- ◆◆ Additional Enhanced specification.

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SOD-523 CASE - MECHANICAL OUTLINE



LEAD CODE:

- 1) Cathode
- 2) Anode

MARKING CODE: 4E

DIMENSIONS				
SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.020	0.031	0.50	0.80
B	0.008	0.016	0.20	0.40
C	0.002	0.008	0.05	0.20
D	0.028	0.035	0.70	0.90
E	0.008	0.014	0.20	0.35
F	0.039	0.055	1.00	1.40
G	0.055	0.071	1.40	1.80
H	0.016		0.40	

SOD-523 (REV: R3)

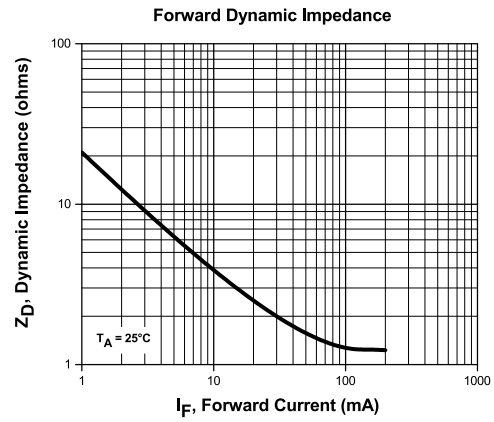
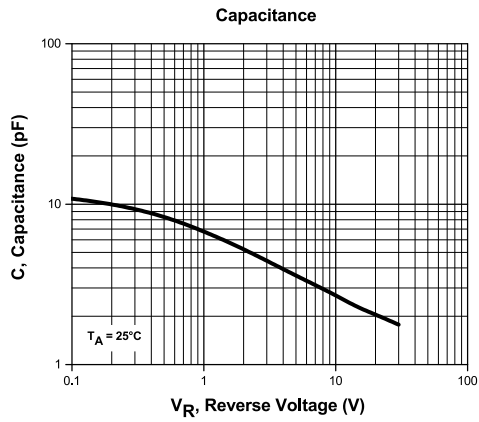
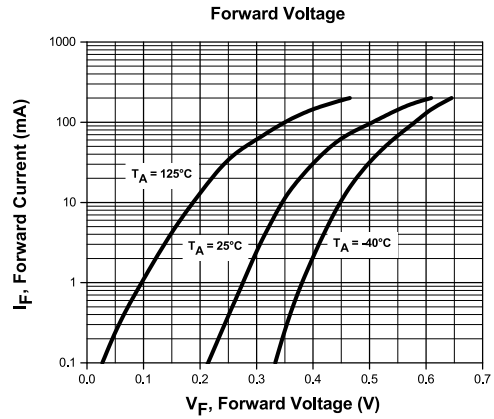
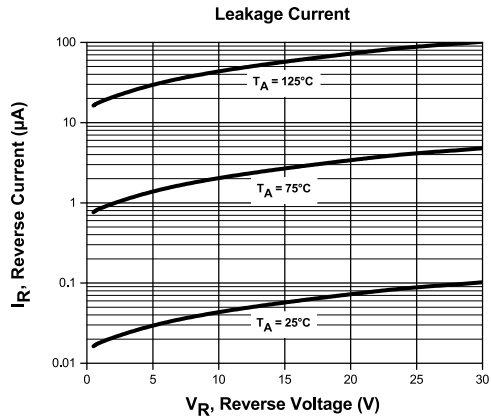
R5 (16-February 2016)

CMOSH-4E

**ENHANCED SPECIFICATION
SURFACE MOUNT SILICON
SCHOTTKY DIODE**



TYPICAL ELECTRICAL CHARACTERISTICS



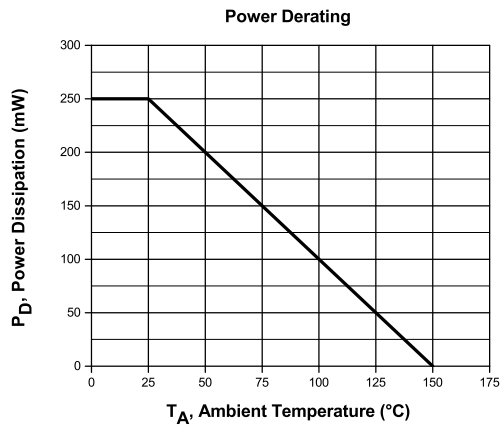
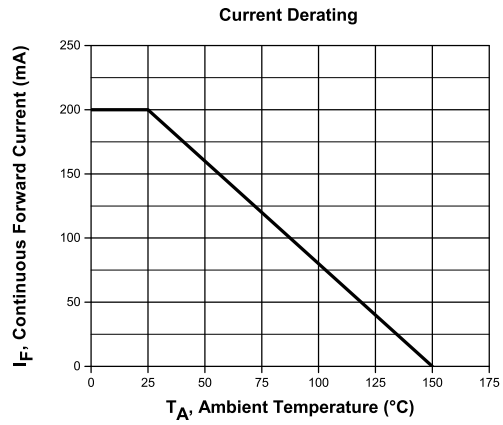
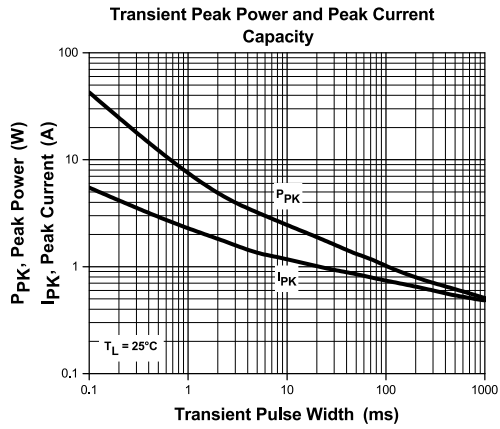
R5 (16-February 2016)

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TYPICAL ELECTRICAL CHARACTERISTICS



R5 (16-February 2016)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

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